Vishay Semiconductors

VS-10WQ045FNPbF

Schottky Rectifier, 10 A



Anode

Base cathode

ÓЗ

Anode

D-PAK (TO-252AA)

PRODUCT SUMMARY			
Package	D-PAK (TO-252AA)		
I _{F(AV)}	10 A		
V _R	45 V		
V _F at I _F	0.53 V		
I _{RM}	15 mA at 125 °C		
T _J max.	175 °C		
Diode variation	Single die		
E _{AS}	20 mJ		

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^\circ\mathrm{C}$

DESCRIPTION

The VS-10WQ045FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	10	А		
V _{RRM}		45	V		
I _{FSM}	t _p = 5 μs sine	400	А		
V _F	10 Apk, T _J = 125 °C	0.53	V		
TJ	Range	- 40 to 175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10WQ045FNPbF	UNITS	
Maximum DC reverse voltage	V _R	45	V	
Maximum working peak reverse voltage	V _{RWM}	45	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 157 °C, rectangular waveform 10		А	
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	400	А
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	75	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.0	А





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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	10 A	T _{.1} = 25 °C	0.63	
		20 A	1j=23 0	0.80	V
		10 A	T _J = 125 °C	0.53	
		20 A		0.71	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1	mA
See fig. 2	IRM \	T _J = 125 °C		15	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.255	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		760	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0		nH	

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		50	0/14
Approximate weight			0.3	g
		0.01	oz.	
Marking device		Case style D-PAK (similar to TO-252AA)	10WQ	045FN

Note

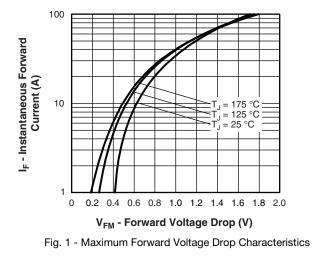
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

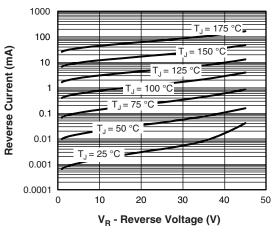


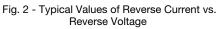
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Schottky Rectifier, 10 A

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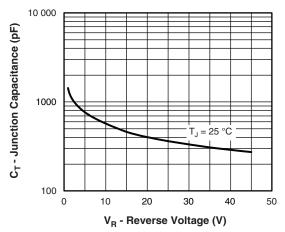


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

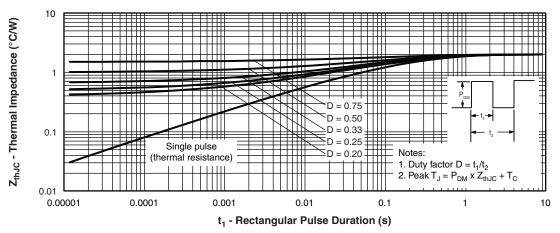


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

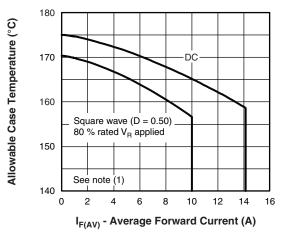
VS-10WQ045FNPbF

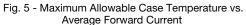
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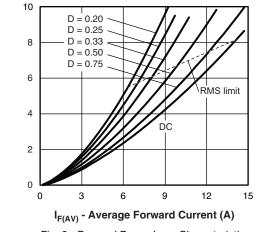
Schottky Rectifier, 10 A

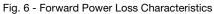
Average Power Loss (W)

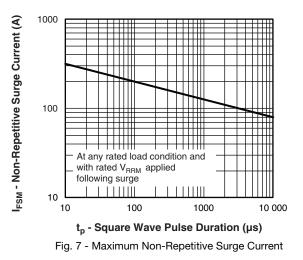












Note

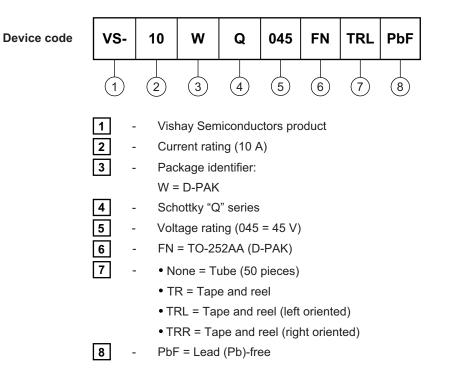
- (1)
- Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 D); I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE

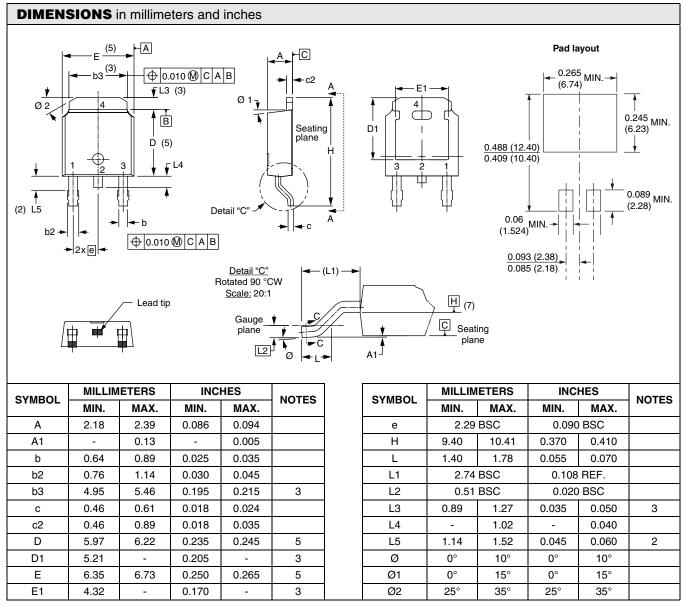


LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95059		
Packaging information	www.vishay.com/doc?95033		



Vishay High Power Products

D-PAK (TO-252AA)



Notes

- $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension uncontrolled in L5
- ⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- ⁽⁵⁾ Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁶⁾ Dimension b1 and c1 applied to base metal only
- ⁽⁷⁾ Datum A and B to be determined at datum plane H
- ⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA



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